

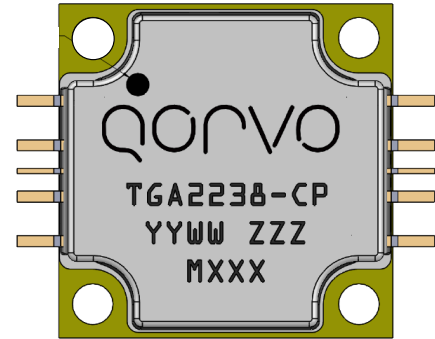
Product Description

Qorvo's TGA2238-CP is a packaged, high power X-band amplifier fabricated on Qorvo's QGaN25 0.25 μm GaN on SiC production process. Operating from 8 – 11 GHz, the TGA2238-CP achieves 50 W saturated output power with 24 dB power gain and 34 % power-added efficiency.

The TGA2238-CP is packaged in a 10-lead 15 x 15 mm bolt-down package with a Cu base for superior thermal management. Both RF ports (RF input internally DC blocked) are matched to 50 ohms allowing for simple system integration.

The TGA2238-CP is ideally suited for both military and commercial X-band radar systems and data links.

Lead-free and RoHS compliant.

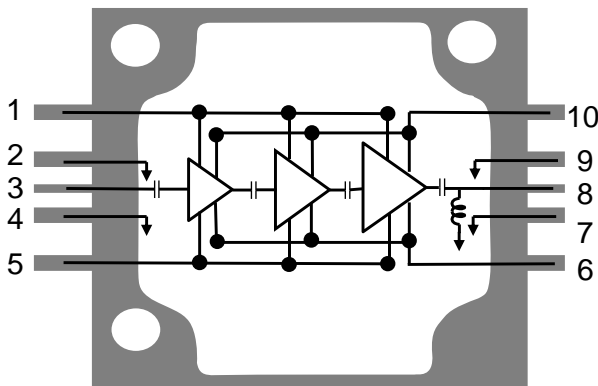


Product Features

- Frequency Range: 8 – 11 GHz
- P_{SAT} : 47 dBm @ $P_{IN} = 23$ dBm
- PAE: 34% @ $P_{IN} = 23$ dBm
- Power Gain: 24 dB @ $P_{IN} = 23$ dBm
- Small Signal Gain: 28 dB
- Return Loss: 9 dB
- Bias: $V_D = +28$ V, $I_{DQ} = 650$ mA
(Pulsed V_D : $PW = 100$ μs and $DC = 10$ %)
- Package Dimensions: 15.2 x 15.2 x 3.5 mm
- Package base is pure Cu offering superior thermal management

Performance is typical across frequency. Please reference electrical specification table and data plots for more details

Functional Block Diagram



Applications

- X-band Radar
- Datalinks

Ordering Information

Part No.	Description
TGA2238-CP	8 – 11 GHz 50 W GaN Power Amplifier
TGA2238-CP EVB	Evaluation Board



TGA2238-CP

8 – 11 GHz 50 W GaN Power Amplifier

Absolute Maximum Ratings

Parameter	Value / Range
Drain Voltage (V_D)	40 V
Gate Voltage Range (V_G)	-8 to 0 V
Drain Current (I_D)	8 A
Gate Current (I_G)	See plot page 9
Power Dissipation (P_{DISS}), 85°C Pulsed: PW = 100 μ s, DC = 10%	158 W
Input Power (P_{IN}), 50 Ω , 85°C, V_D = 28V, Pulsed: PW = 100 μ s, DC = 10%	30 dBm
Input Power (P_{IN}), 85°C, VSWR 3:1, V_D = 28V, Pulsed: PW = 100 μ s, DC = 10%	30 dBm
Mounting Temperature	Refer to Assembly Notes, page 13
Storage Temperature	-55 to 150 °C

Operation of this device outside the parameter ranges given above may cause permanent damage. These are stress ratings only, and functional operation of the device at these conditions is not implied.

Electrical Specifications

Parameter		Min	Typ	Max	Units
Operational Frequency Range		8		11	GHz
Small Signal Gain			28		dB
Input Return Loss			9		dB
Output Return Loss			10		dB
Output Power (P_{IN} = 23 dBm)	8 GHz	46	47		dBm
	9 GHz	46	47		dBm
	10 GHz	46	47		dBm
	11 GHz	46	47		dBm
Power Added Eff. (P_{IN} = 23 dBm)	8 GHz	28	34		%
	9 GHz	32	34		%
	10 GHz	31	34		%
	11 GHz	30	34		%
Power Gain (P_{IN} = 23 dBm)			24		dB
Gate Leakage (V_D = +10 V, V_G = -3.7V)		-29			mA
Small Signal Gain Temperature Coefficient			-0.056		dBm/°C
Power Temperature Coefficient (P_{IN} =23 dBm)			-0.001		dBm/°C

Test conditions unless otherwise noted: 25 °C, V_D = +28 V, I_{DQ} = 650 mA, Pulsed V_D : PW = 100 μ s, DC = 10 %

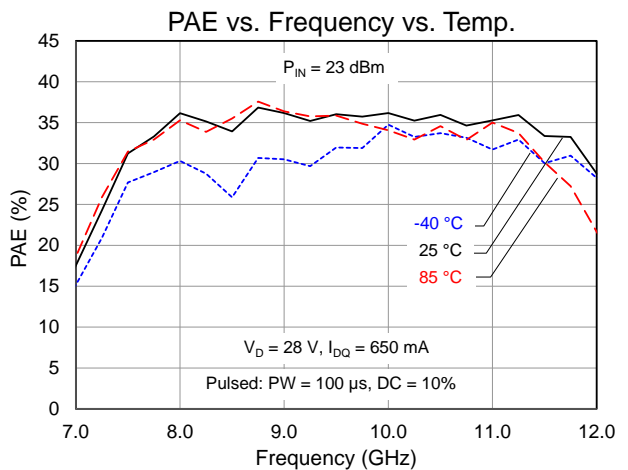
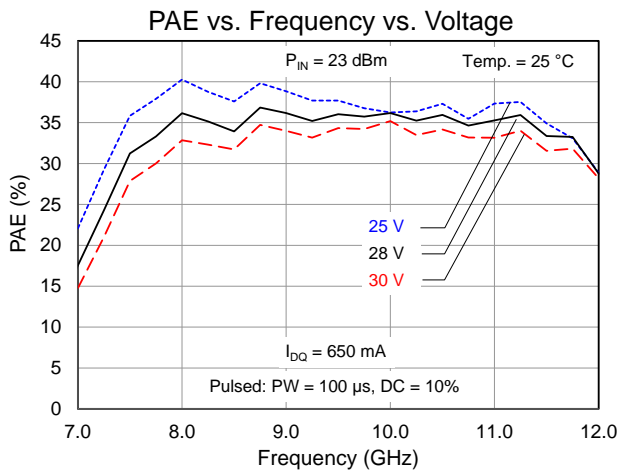
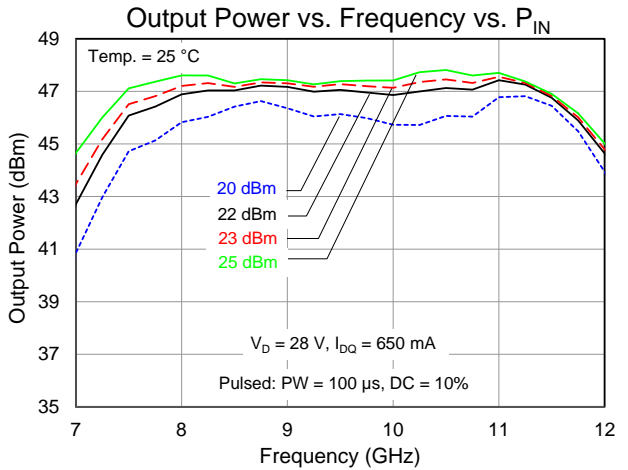
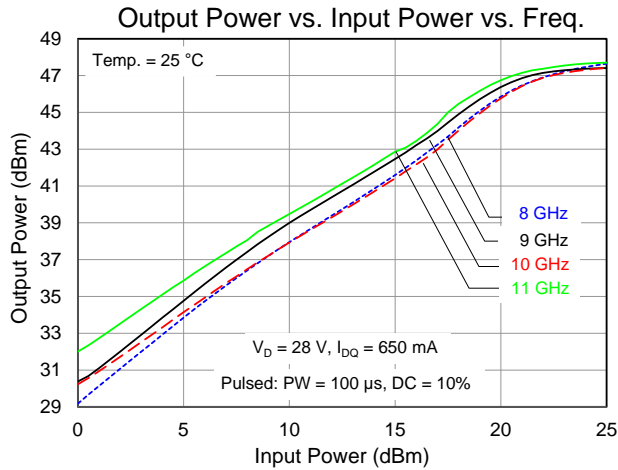
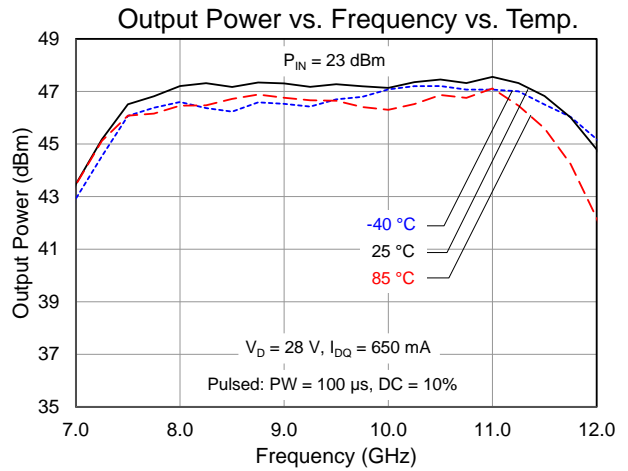
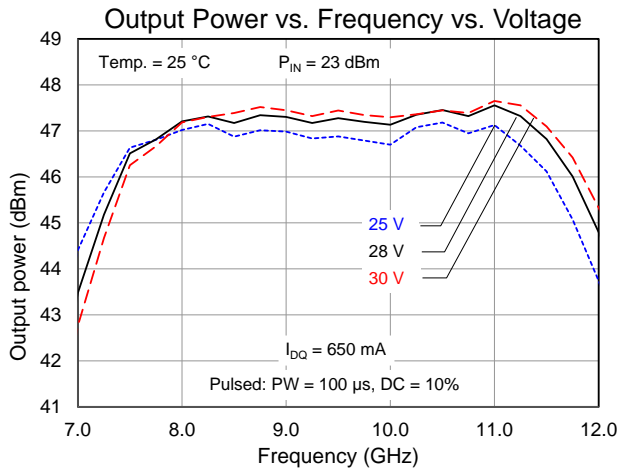
Recommended Operating Conditions

Parameter	Value / Range
Input Power (P_{IN})	Pulsed: 23 dBm
	CW: 20 dBm ^{1/}
Drain Voltage (V_D)	28 V
Drain Current (I_{DQ})	650 mA
Temperature Range	-40 to +85 °C

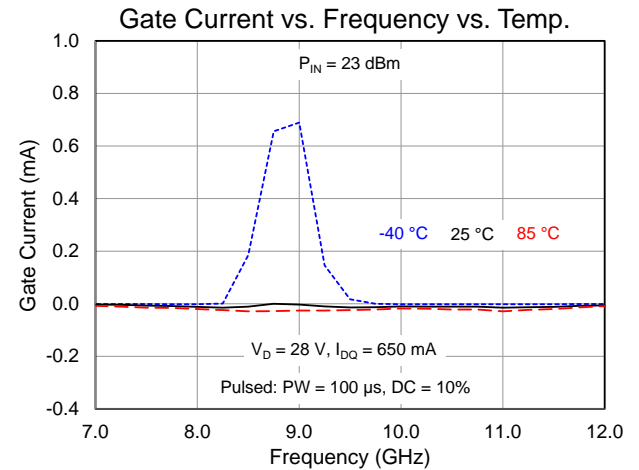
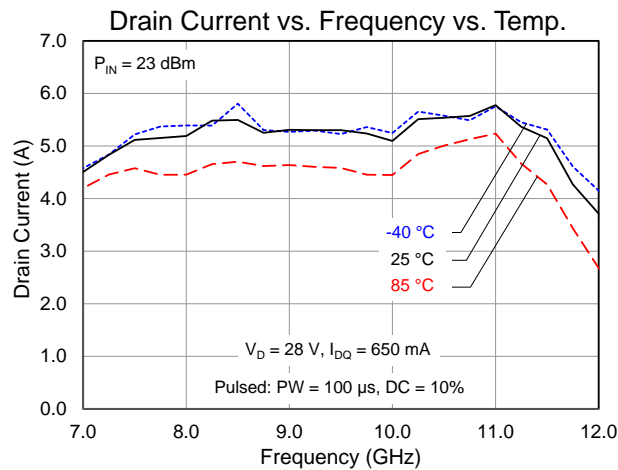
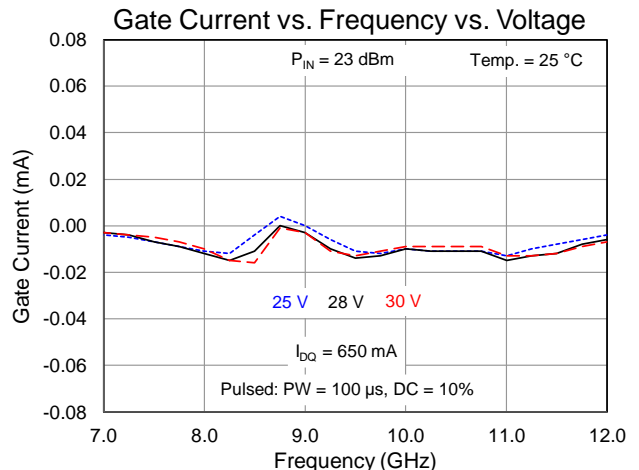
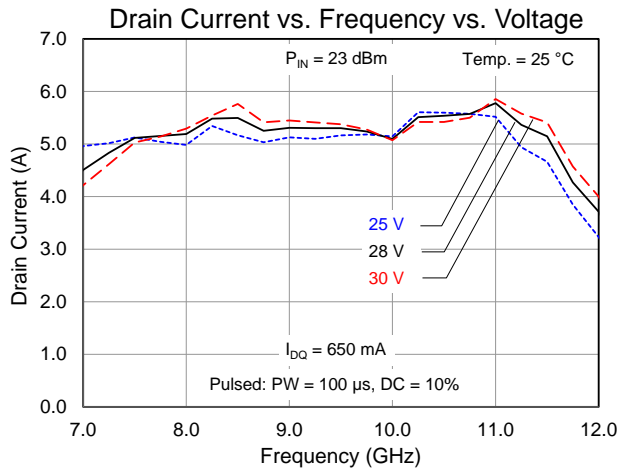
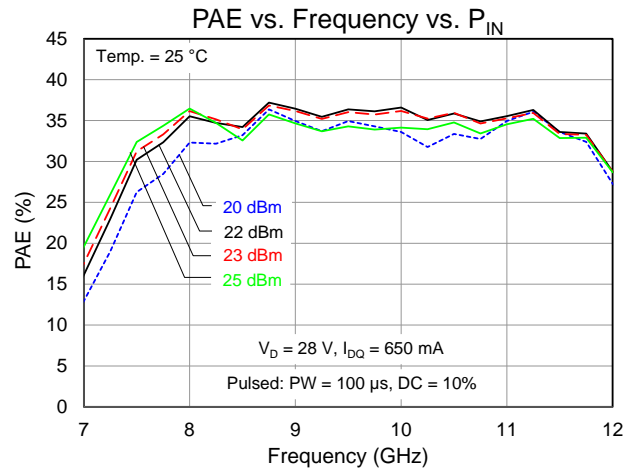
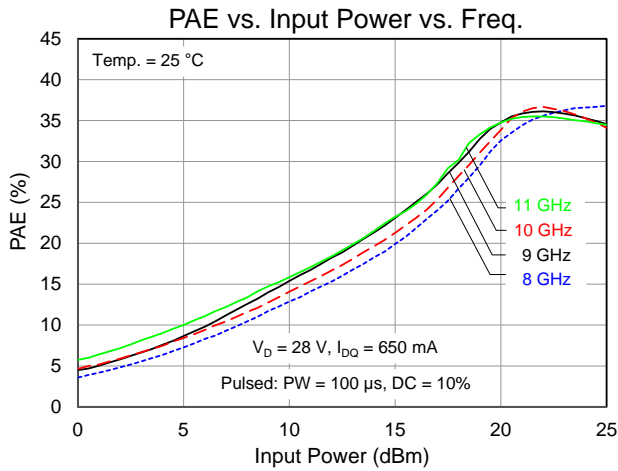
^{1/} CW operating requires thermal consideration; CW applications are up to 2 dBm back off from saturated output power P_{SAT} .

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

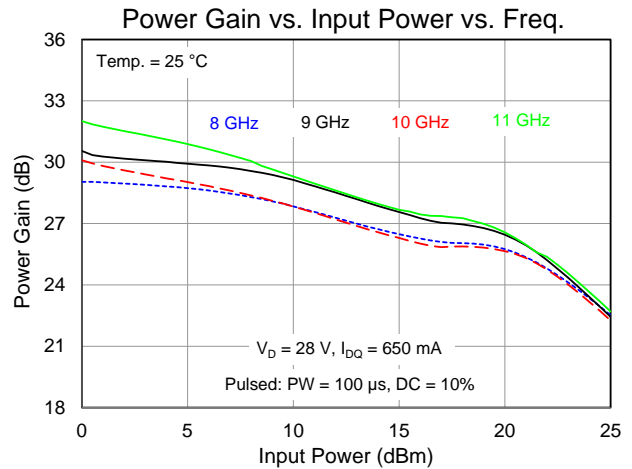
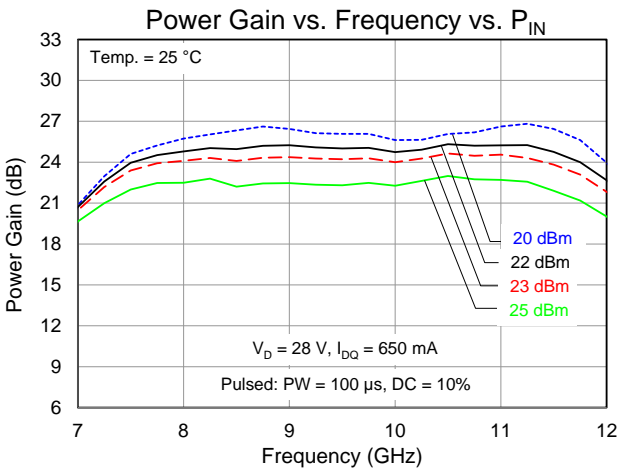
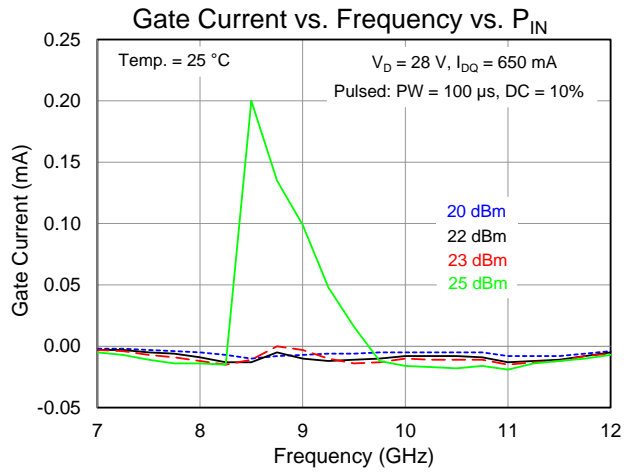
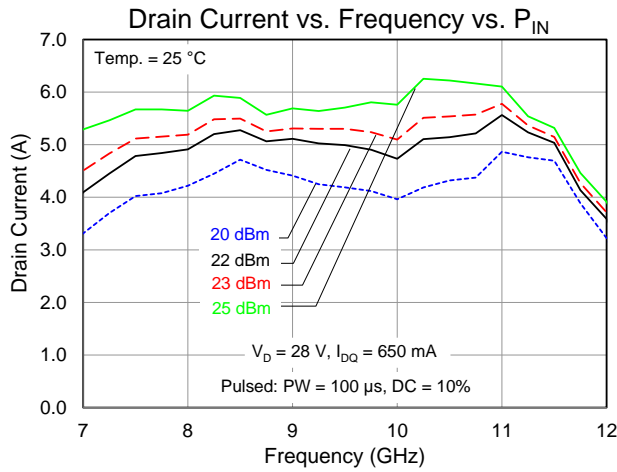
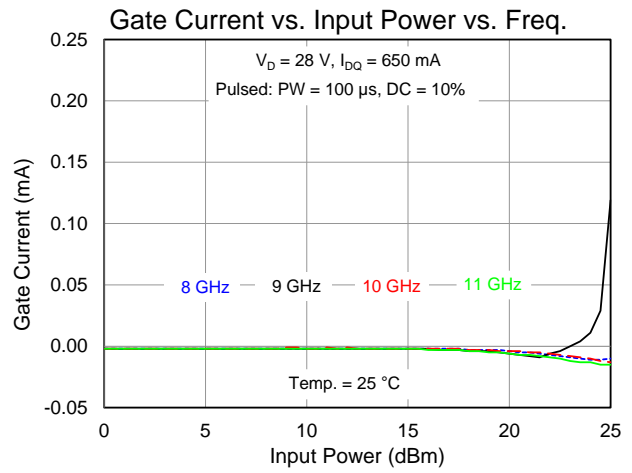
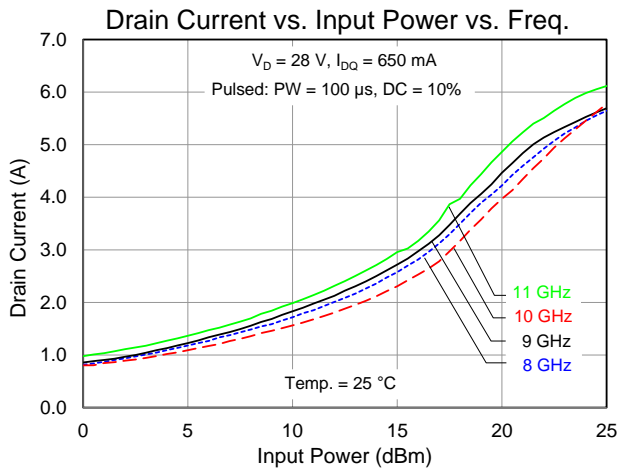
Typical Performance – Large Signal (Pulsed)



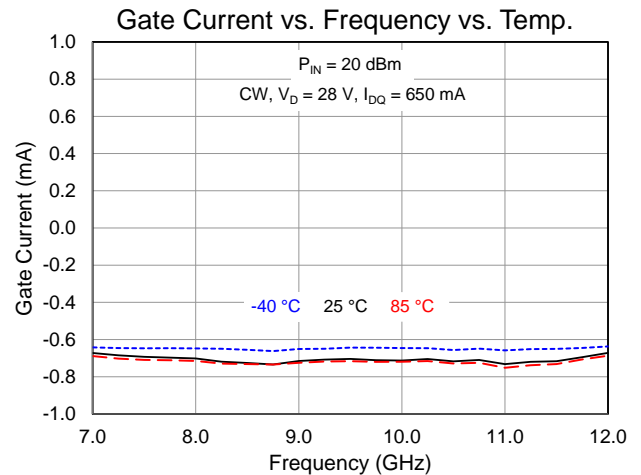
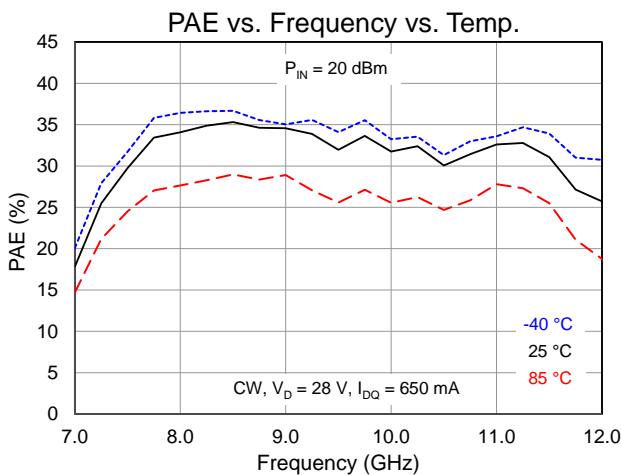
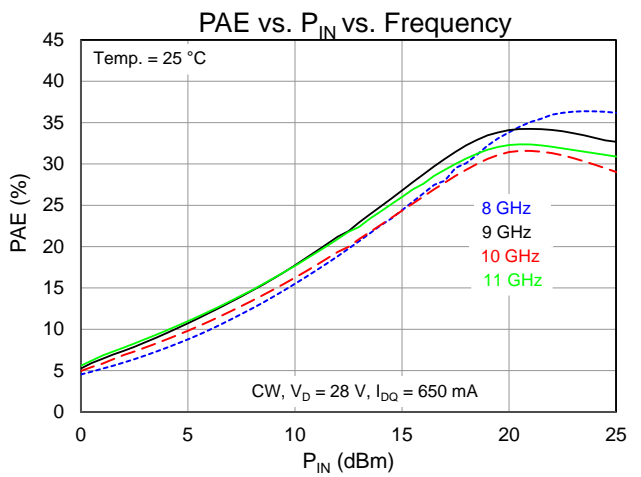
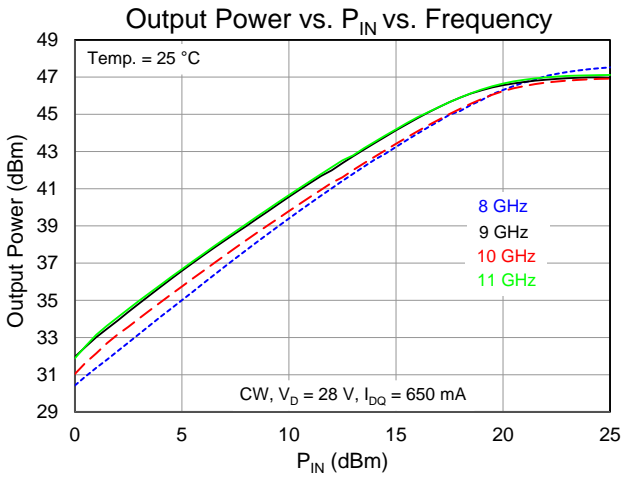
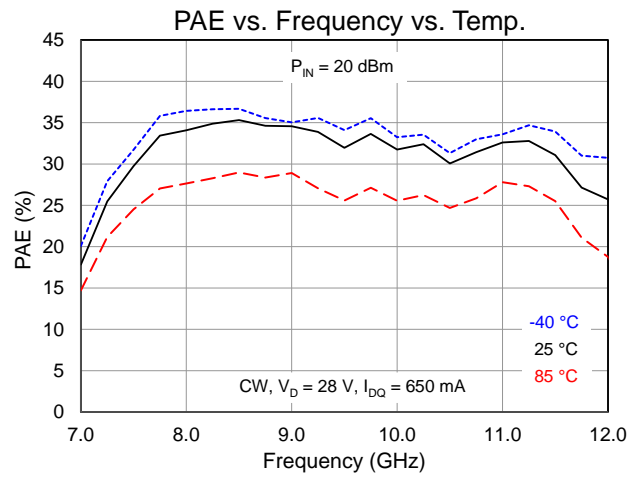
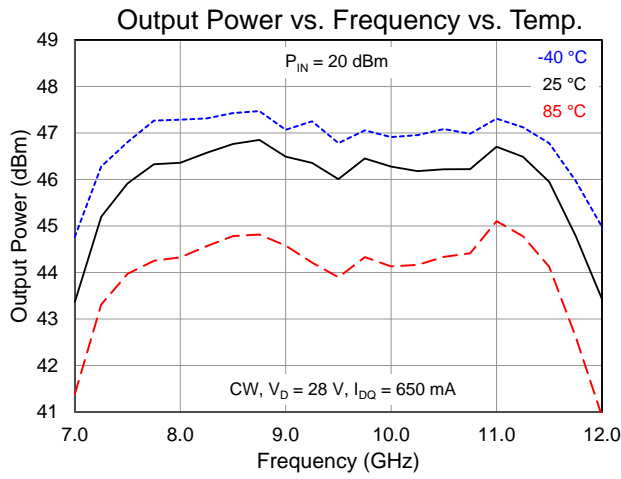
Typical Performance – Large Signal (Pulsed)



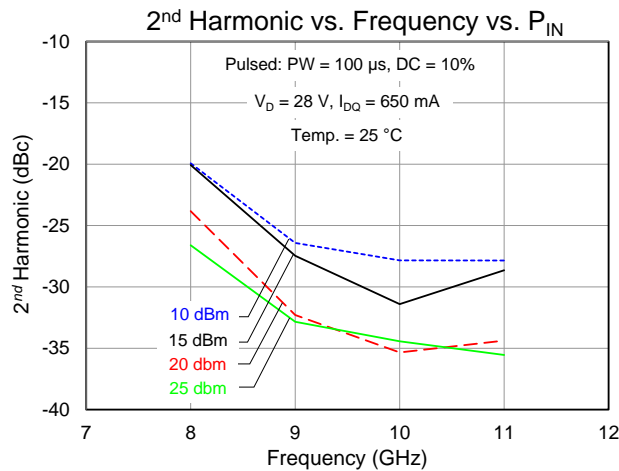
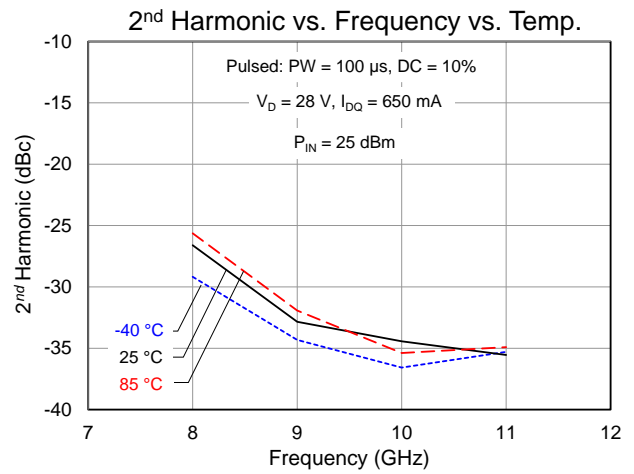
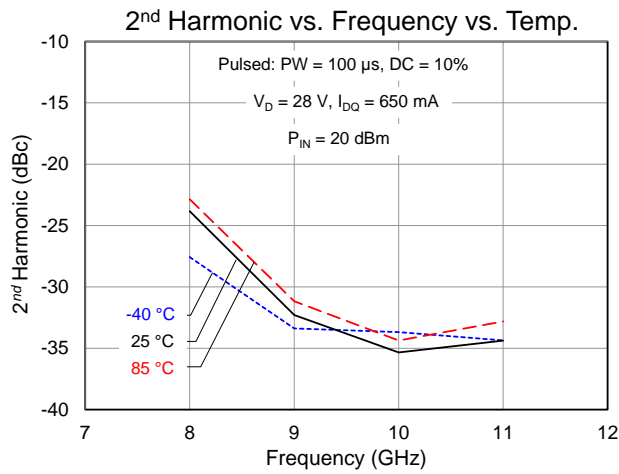
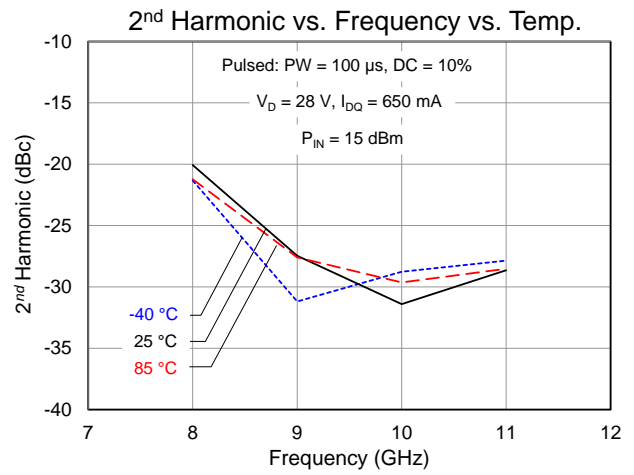
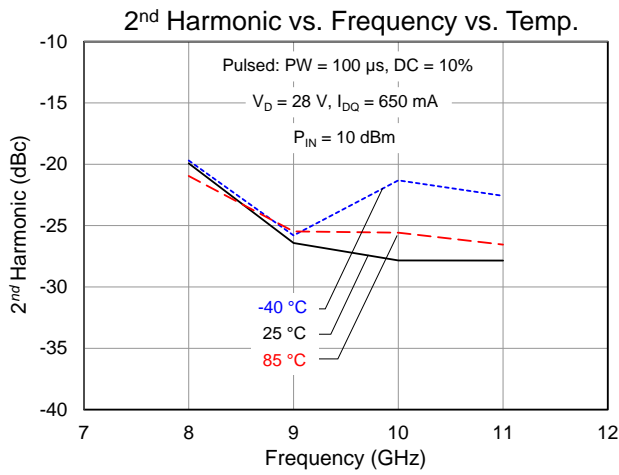
Typical Performance – Large Signal (Pulsed)



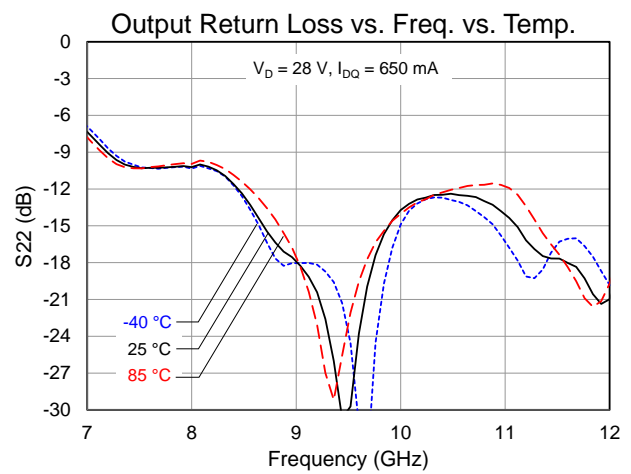
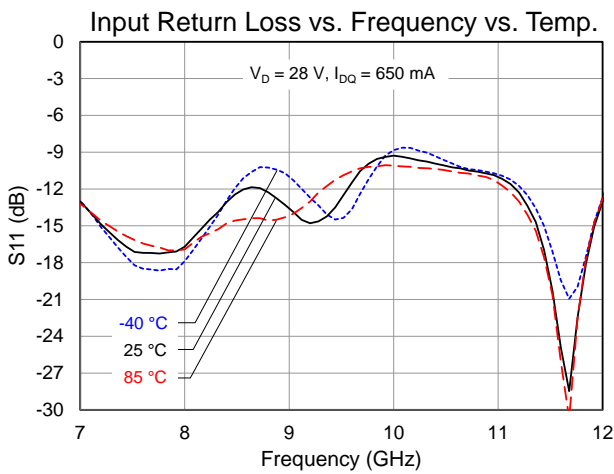
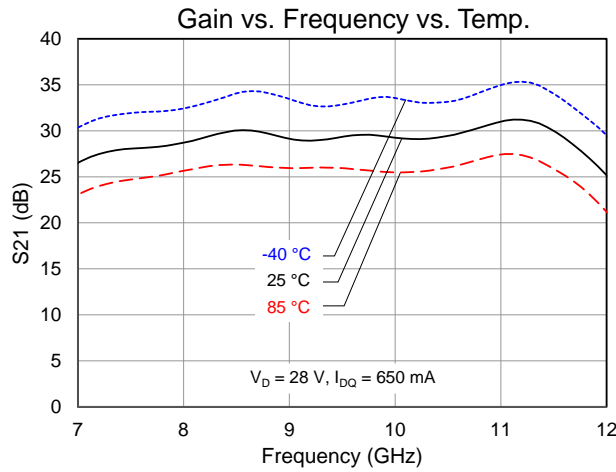
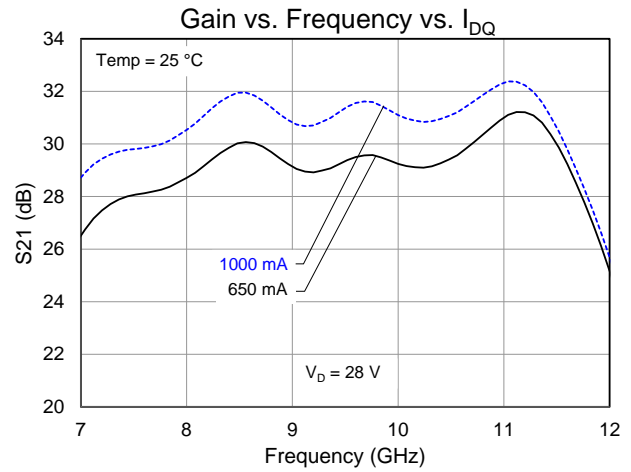
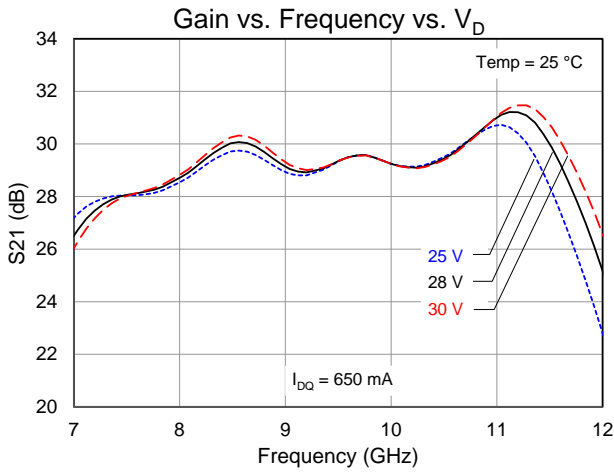
Typical Performance – Large Signal (CW)



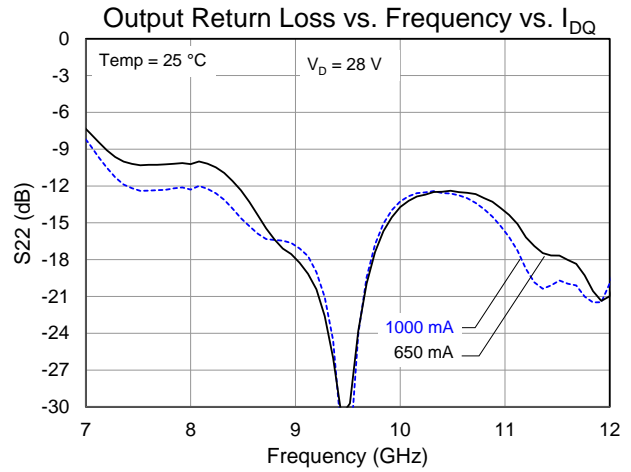
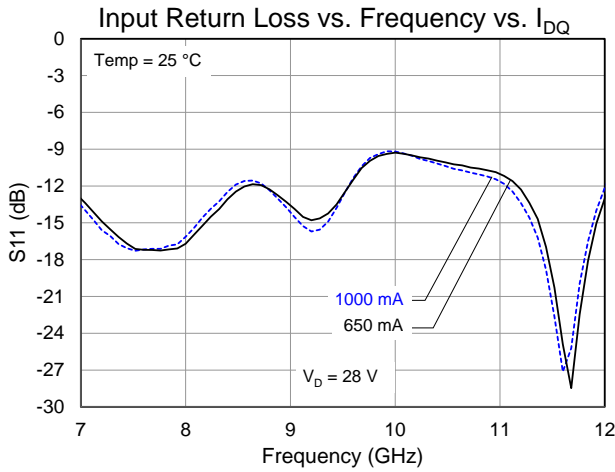
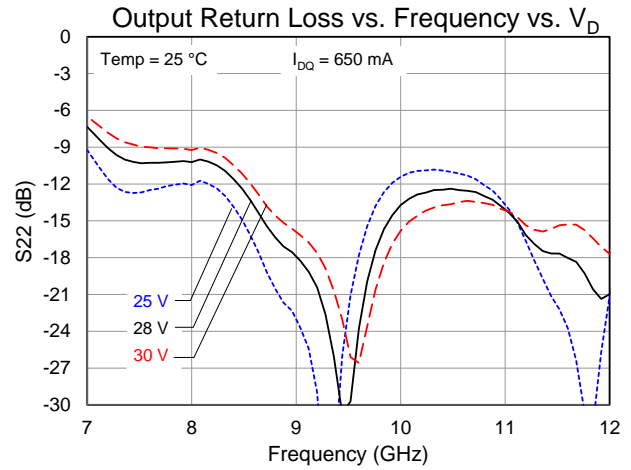
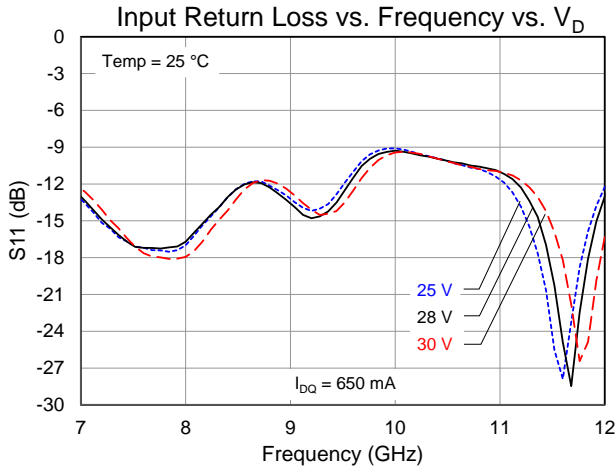
Performance Plots – Large Signal (Pulsed)



Performance Plots – Small Signal (CW)



Performance Plots – Small Signal (CW)



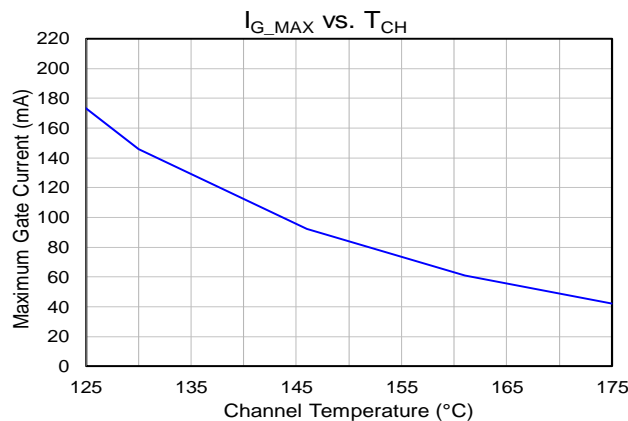
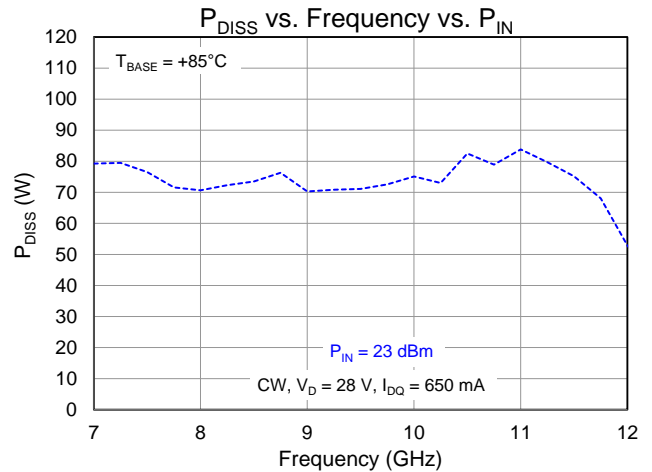
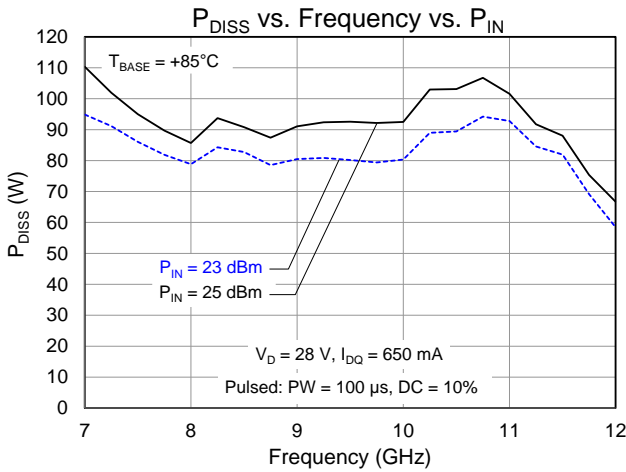
Thermal and Reliability Information

Parameter	Test Conditions	Value	Units
Thermal Resistance (θ_{JC}) ⁽¹⁾	$V_D = 28\text{ V}$, $I_{DQ} = 650\text{ mA}$,	0.33	$^{\circ}\text{C}/\text{W}$
Channel Temperature, T_{CH} (No RF) ⁽²⁾	$T_{base} = 85\text{ }^{\circ}\text{C}$, $P_{DISS} = 18.2\text{ W}$ (Quiescent)	91	$^{\circ}\text{C}$
Thermal Resistance (θ_{JC}) ⁽¹⁾	Pulsed V_D : $T_{BASE} = 85\text{ }^{\circ}\text{C}$, $V_D = 28\text{ V}$, $I_{DQ} = 650\text{ mA}$,	0.52	$^{\circ}\text{C}/\text{W}$
Channel Temperature, T_{CH} (Under RF) ⁽²⁾	$I_{D_Drive} = 5.9\text{ A}$, $PW = 100\text{ }\mu\text{s}$, $DC = 10\%$, $P_{IN} = 25\text{ dBm}$, $P_{OUT} = 47.5\text{ dBm}$, $P_{DISS} = 108\text{ W}$	141	$^{\circ}\text{C}$
Thermal Resistance (θ_{JC}) ⁽¹⁾	CW: $T_{BASE} = 85\text{ }^{\circ}\text{C}$, $V_D = 28\text{ V}$, $I_{DQ} = 650\text{ mA}$, I_{D_Drive}	0.74	$^{\circ}\text{C}/\text{W}$
Channel Temperature, T_{CH} (Under RF) ⁽²⁾	$= 4.15\text{ A}$, Frequency = 11 GHz , $P_{IN} = 20\text{ dBm}$, $P_{OUT} = 45\text{ dBm}$, $P_{DISS} = 83.8\text{ W}$	147	$^{\circ}\text{C}$

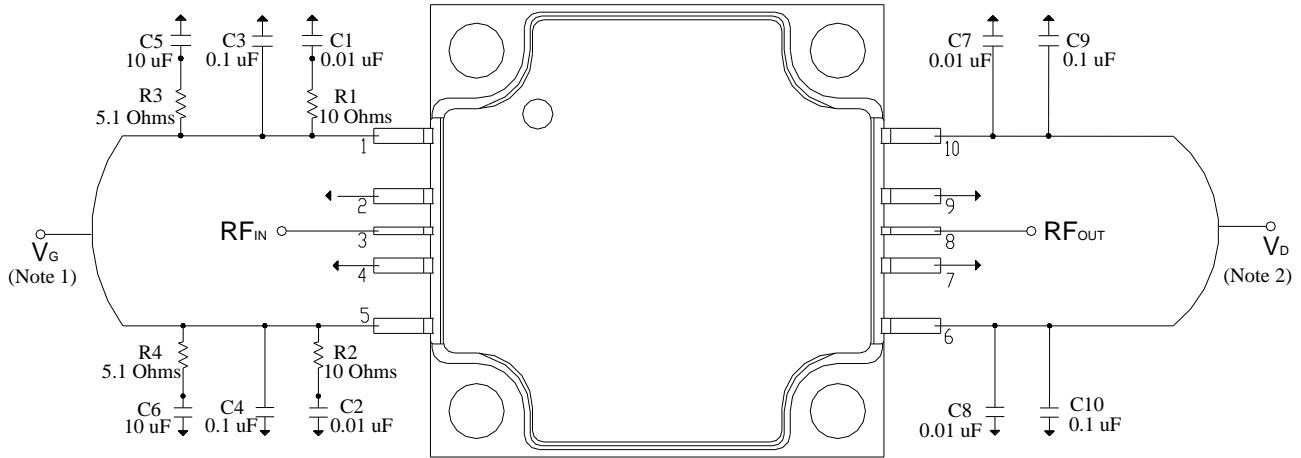
Notes:

1. Thermal resistance is referenced to the back of package ($85\text{ }^{\circ}\text{C}$)
2. Refer to the following document: [GaN Device Channel Temperature, Thermal Resistance, and Reliability Estimates](#)

Dissipated Power and Maximum Gate Current



Applications Information and Pin Layout



Notes:

1. V_G must be biased from both sides (Pins 1 and 5)
2. V_D must be biased from both sides (Pins 6 and 10)

Bias Up Procedure

1. Set I_D limit to 7 A, I_G limit to 20 mA
2. Apply -5 V to V_G
3. Apply 28 V to V_D ; ensure I_{DQ} is approx. 0 mA
4. Adjust V_G until $I_{DQ} = 650\text{ mA}$
5. Turn on RF supply

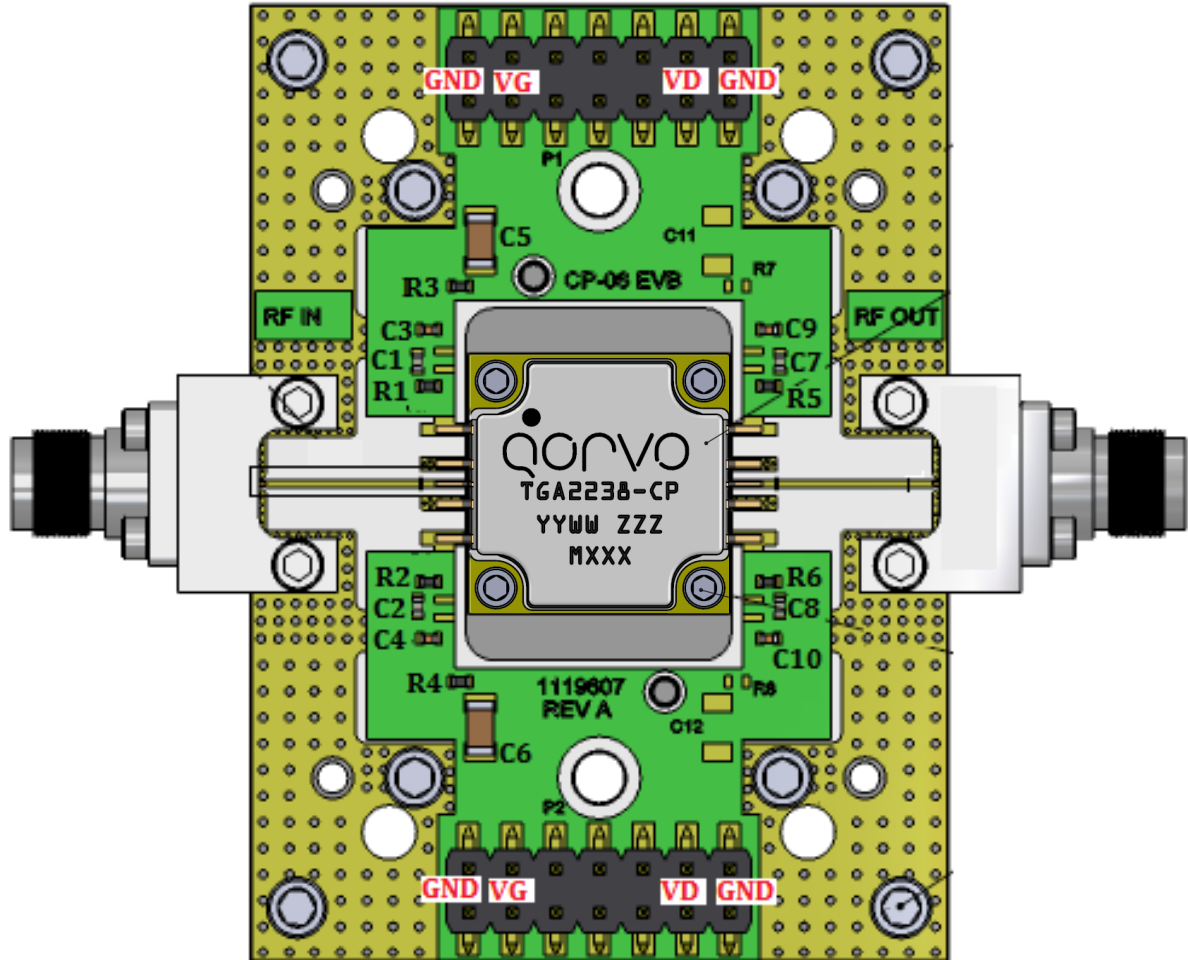
Bias Down Procedure

1. Turn off RF supply
2. Reduce V_G to -5 V ; ensure I_{DQ} is approx. 0 mA
3. Set V_D to 0 V
4. Turn off V_D supply
5. Turn off V_G supply

Pin Description

Pad No.	Symbol	Description
1,5	V_G	Gate Voltage; Bias network is required; must be biased from both sides; see recommended Application Information above.
2,4,7,9	GND	Must be grounded on the PCB.
3	RF_{IN}	Input; matched to $50\ \Omega$; DC blocked
6,10	V_D	Drain voltage; Bias network is required; must be biased from both sides; see recommended Application Information above.
8	RF_{OUT}	Output; matched to $50\ \Omega$; DC shorted to ground.

Evaluation Board (EVB) Assembly Drawing



PCB NOTES:

1. PCB is made from Rogers 4003C dielectric, 0.008 inch thick, 0.5 oz. copper both sides.
2. Both Top and Bottom V_D and V_G must be biased.

Bill of Materials

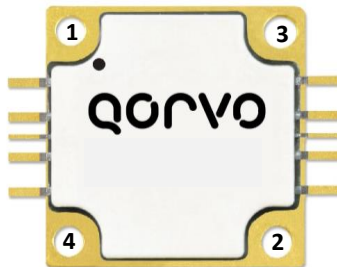
Reference Des.	Value	Description	Manuf.	Part Number
C1, C2, C7, C8	0.01 uF	Cap, 0402, 50 V, 10%, X7R	Various	–
C3, C4, C9, C10	0.1 uF	Cap, 0402, 50 V, 10%, X7R	Various	–
C5, C6	10 uF	Cap, 1206, 50 V, 20%, X5R	Various	–
R1, R2	10 Ω	Res, 0402, 5%, SMD	Various	–
R3, R4	5.1 Ω	Res, 0402, 5%, ROHS	Various	–
R5, R6	0 Ω	Res, 0402, SMD, jumpers required for the above EVB	Various	–

Assembly Notes

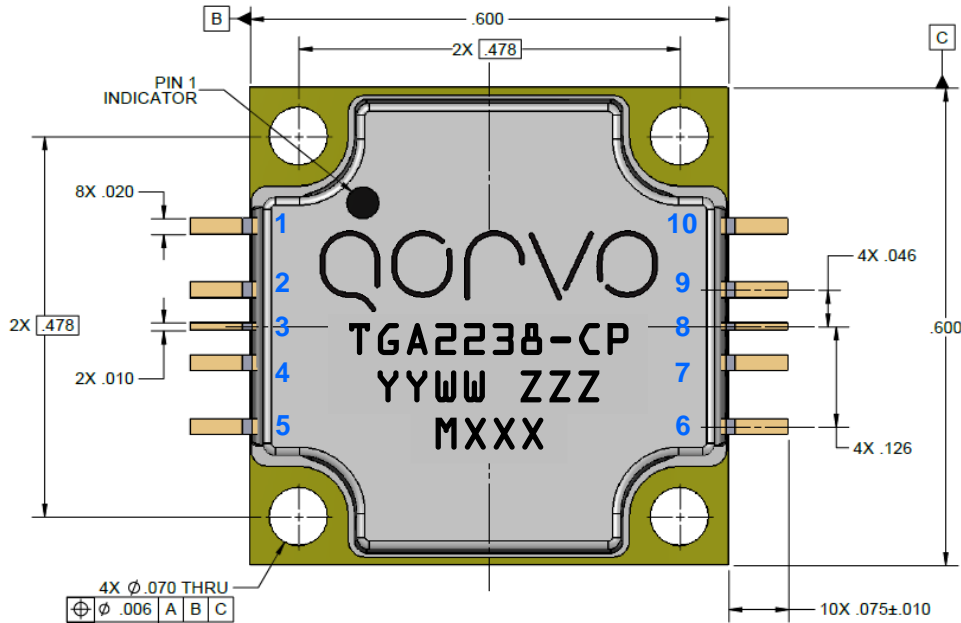
1. Carefully clean the PC board, base plate, and package leads with alcohol. Allow it to dry fully.
2. To improve the thermal and RF performance, Qorvo recommends attaching a heat sink to the bottom of the package and apply either a thermal compound (Arctic Silver 5 recommended) or a .004 inch (maximum thickness) Indium shim between the heat sink and the package. Refer to the applications note [Application of Arctic Silver 5 Thermal Compound and Indium Shims for Qorvo CP-style Packaged Components](#) for more information.
3. The component leads should be manually soldered. Apply a low residue solder alloy meeting J-STD-001 (ROL0, ROL1 or equivalent) with a liquidus temperature below 220 °C to each pin of the TGA2238-CP. The use of low residue/no-clean flux (ROL0, ROL1) is recommended. The package lead temperature should not exceed 260 deg C. Each solder connection should be completed within 2 to 5 seconds. Adding flux during hand soldering of the component leads with localized spot cleaning is acceptable. Soldering irons meeting the requirements of J-STD-001, Appendix A are acceptable.
4. The leads should be soldered in a staggered or star pattern from side to side, and never solder two adjacent leads. This allows the heat to dissipate on each lead, and not cause the adjacent leads to become de-soldered and damaged or displaced.



5. The packaged part should not be subjected to conventional SMT automated solder reflow processes.
6. (The following is for information only. There are many variables in a second level assembly that Qorvo does not control, so Qorvo does not recommend an absolute torque value.) Use screws to attach the component to the heat sink. A suggested final torque value is 16 in-oz. for a 0-80 screw. Start with screws finger tight, then torque to 8 in-oz., then torque to final value. Use the following tightening pattern:

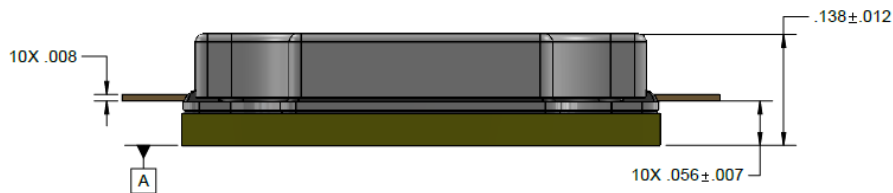


Mechanical Information



NOTES:

1. MATERIALS
 PACKAGE BASE: COPPER
 LEADS: ALLOY 194
 LID: PLASTIC
 FINISH: GOLD
2. PART IS EPOXY SEALED
3. UNITS: INCHES
4. TOLERANCES (UNLESS NOTED):
 .XX = ± .01
 .XXX = ± .005
5. MARKINGS
 PART NUMBER: TGA2238-CP
 WORK YEAR: YY
 WORK WEEK: WW
 SERIAL NUMBER: ZZZ
 BATCH ID: MXXX



Handling Precautions

Parameter	Rating	Standard
ESD – Human Body Model (HBM)	Class 1B	JEDEC Standard JESD22 A114
ESD – Charge Device Model (CDM)	Class C2	JEDEC Standard JESD22-C101F
MSL – Moisture Sensitivity Level	N/A	



Caution!
ESD-Sensitive Device

Solderability

The component leads should be manually soldered, and the package cannot be subjected to conventional reflow processes. The use of no-clean solder to avoid washing after soldering is recommended.

RoHS Compliance

This product is compliant with the 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment), as amended by Directive 2015/863/EU. This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C₁₅H₁₂Br₄O₂) Free
- PFOS Free
- SVHC Free

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

Web: www.qorvo.com

Tel: 1-844-890-8163

Email: customer.support@qorvo.com

Important Notice

The information contained herein is believed to be reliable; however, Qorvo makes no warranties regarding the information contained herein and assumes no responsibility or liability whatsoever for the use of the information contained herein. All information contained herein is subject to change without notice. Customers should obtain and verify the latest relevant information before placing orders for Qorvo products. The information contained herein or any use of such information does not grant, explicitly or implicitly, to any party any patent rights, licenses, or any other intellectual property rights, whether with regard to such information itself or anything described by such information. **THIS INFORMATION DOES NOT CONSTITUTE A WARRANTY WITH RESPECT TO THE PRODUCTS DESCRIBED HEREIN, AND QORVO HEREBY DISCLAIMS ANY AND ALL WARRANTIES WITH RESPECT TO SUCH PRODUCTS WHETHER EXPRESS OR IMPLIED BY LAW, COURSE OF DEALING, COURSE OF PERFORMANCE, USAGE OF TRADE OR OTHERWISE, INCLUDING THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE.**

Without limiting the generality of the foregoing, Qorvo products are not warranted or authorized for use as critical components in medical, life-saving, or life-sustaining applications, or other applications where a failure would reasonably be expected to cause severe personal injury or death.

Copyright 2023 © Qorvo, Inc. | Qorvo is a registered trademark of Qorvo, Inc.

Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

 [View TGA2238-CP on WIN SOURCE](#)

 [Qorvo US Inc. Information](#)

Optimize Your Supply Chain with WIN SOURCE Solutions

-  Global Sourcing Solution
-  Obsolete Management
-  Cost Control Management
-  Shortage Management
-  Alternative Solution
-  Excess Inventory Management